## RELIABILITY REPORT

FOR

## MAX4214EUK

## PLASTIC ENCAPSULATED DEVICES

May 6, 2003

## **MAXIM INTEGRATED PRODUCTS**

120 SAN GABRIEL DR. SUNNYVALE, CA 94086

Written by

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#### Conclusion

The MAX4214 successfully meets the quality and reliability standards required of all Maxim products. In addition, Maxim's continuous reliability monitoring program ensures that all outgoing product will continue to meet Maxim's quality and reliability standards.

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## I. Device Description

#### A. General

The MAX4214 is a precision, closed-loop, gain of +2 (or -1) buffer featuring high slew rates, high output current drive, and low differential gain and phase error. It operates with a single +3.15V to +11V supply or with  $\pm1.575$ V to  $\pm5.5$ V dual supplies. The input common-mode voltage range extends 100mV beyond the negative power-supply rail, and the output swings Rail-to-Rail  $\circledast$ .

This devices requires only 5.5mA of quiescent supply current while achieving a 230MHz  $\underline{\hspace{0.1cm}}$ -3dB bandwidth and a 600V/µs slew rate. Input voltage noise is only 10nV/ $\sqrt{\hspace{0.1cm}}$ Hz, and input current noise is only 1.3pA/ $\sqrt{\hspace{0.1cm}}$ Hz. This buffer is ideal for low-power/low-voltage applications requiring wide bandwidth, such as video, communications, and instrumentation systems.

Rating

#### B. Absolute Maximum Ratings

Item

	<del></del>
Supply Voltage (VCC to VEE) IN, IN_+, OUT_, EN_ Output Short-Circuit Duration to VCC or VEE Operating Temperature Range	12V (VEE - 0.3V) to (VCC + 0.3V) Continuous -40°C to +85°C
Storage Temperature Range	-65°C to +150°C
Lead Temperature (soldering, 10s) Continuous Power Dissipation	+300°C
5-Lead SOT23	571mW
Derates above +70°C 5-Lead SOT23	7.1mW/°C

## II. Manufacturing Information

A. Description/Function: High-Speed, Single-Supply, Gain of +2, Closed-Loop, Rail-to-Rail Buffer with Enable

B. Process: CB2 (Complementary Bipolar Process)

C. Number of Device Transistors: 95

D. Fabrication Location: Oregon, USA

E. Assembly Location: Malaysia or Thailand

F. Date of Initial Production: December, 1997

## **III. Packaging Information**

A. Package Type: 5 Lead SOT-23

B. Lead Frame: Copper

C. Lead Finish: Solder Plate

D. Die Attach: Silver-filled Epoxy

E. Bondwire: Gold (1 mil dia.)

F. Mold Material: Epoxy with silica filler

G. Assembly Diagram: # 05-3001-0040

H. Flammability Rating: Class UL94-V0

I. Classification of Moisture Sensitivity

per JEDEC standard JESD22-A112: Level 1

#### IV. Die Information

A. Dimensions: 57 x 38 mils

B. Passivation: Si<sub>3</sub>N<sub>4</sub>/SiO<sub>2</sub> (Silicon nitride/ Silicon dioxide)

C. Interconnect: Gold

D. Backside Metallization: None

E. Minimum Metal Width: 2 microns (as drawn)

F. Minimum Metal Spacing: 2 microns (as drawn)

G. Bondpad Dimensions: 5 mil. Sq.

H. Isolation Dielectric: SiO<sub>2</sub>

I. Die Separation Method: Wafer Saw

#### V. Quality Assurance Information

A. Quality Assurance Contacts:

Jim Pedicord (Manager, Reliability Operations)
Bryan Preeshl (Executive Director of QA)
Kenneth Huening (Vice President)

B. Outgoing Inspection Level: 0.1% for all electrical parameters guaranteed by the Datasheet.

0.1% For all Visual Defects.

C. Observed Outgoing Defect Rate: < 50 ppm

D. Sampling Plan: Mil-Std-105D

## VI. Reliability Evaluation

#### A. Accelerated Life Test

The results of the 135°C biased (static) life test are shown in **Table 1**. Using these results, the Failure Rate ( $\lambda$ ) is calculated as follows:

$$\lambda = \frac{1}{\text{MTTF}} = \frac{1.83}{192 \times 4389 \times 320 \times 2}$$
 (Chi square value for MTTF upper limit)
$$\frac{1}{192 \times 4389 \times 320 \times 2}$$
 Thermal acceleration factor assuming a 0.8eV activation energy
$$\lambda = 3.39 \times 10^{-9}$$
  $\lambda = 3.39 \text{ F.I.T.}$  (60% confidence level @ 25°C)

This low failure rate represents data collected from Maxim's reliability qualification and monitor programs. Maxim also performs weekly Burn-In on samples from production to assure the reliability of its processes. The reliability required for lots which receive a burn-in qualification is 59 F.I.T. at a 60% confidence level, which equates to 3 failures in an 80 piece sample. Maxim performs failure analysis on lots exceeding this level. The following Burn-In Schematic (Spec. # 06-5215) shows the static circuit used for this test. Maxim also performs 1000 hour life test monitors quarterly for each process. This data is published in the Product Reliability Report (RR-1M).

#### B. Moisture Resistance Tests

Maxim evaluates pressure pot stress from every assembly process during qualification of each new design. Pressure Pot testing must pass a 20% LTPD for acceptance. Additionally, industry standard 85°C/85%RH or HAST tests are performed quarterly per device/package family.

## C. E.S.D. and Latch-Up Testing

The OP05-1 die type has been found to have all pins able to withstand a transient pulse of  $\pm 2000$ V, per Mil-Std-883 Method 3015 (reference attached ESD Test Circuit). Latch-Up testing has shown that this device withstands a current of  $\pm 250$ mA.

# **Table 1**Reliability Evaluation Test Results

## MAX4214EUK

TEST ITEM	TEST CONDITION	FAILURE IDENTIFICATION	SAMPLE SIZE	NUMBER OF FAILURES
Static Life Tes	t (Note 1)			
	Ta = 135°C Biased Time = 192 hrs.	DC Parameters & functionality	320	0
Moisture Testi	ng (Note 2)			
Pressure Pot	Ta = 121°C P = 15 psi. RH= 100% Time = 168hrs.	DC Parameters & functionality	77	0
85/85	Ta = 85°C RH = 85% Biased Time = 1000hrs.	DC Parameters & functionality	77	0
Mechanical St	tress (Note 2)			
Temperature Cycle	-65°C/150°C 1000 Cycles Method 1010	DC Parameters & functionality	77	0

Note 1: Life Test Data may represent plastic D.I.P. qualification lots.

Note 2: Generic Package/Process data

#### Attachment #1

TABLE II. Pin combination to be tested. 1/2/

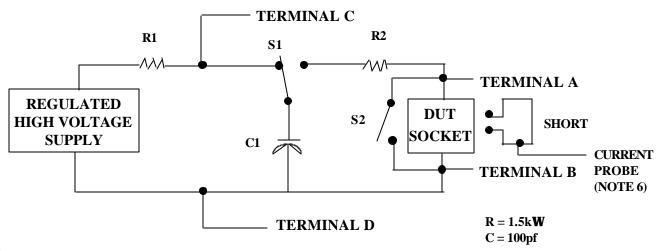
	Terminal A (Each pin individually connected to terminal A with the other floating)	Terminal B (The common combination of all like-named pins connected to terminal B)
1.	All pins except V <sub>PS1</sub> 3/	All V <sub>PS1</sub> pins
2.	All input and output pins	All other input-output pins

- 1/ Table II is restated in narrative form in 3.4 below.
- 2/ No connects are not to be tested.
- 3/ Repeat pin combination I for each named Power supply and for ground

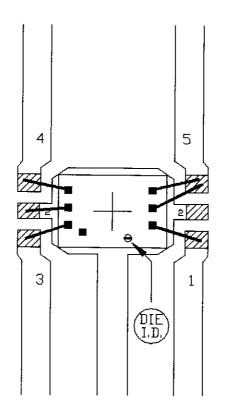
(e.g., where  $V_{PS1}$  is  $V_{DD}$ ,  $V_{CC}$ ,  $V_{SS}$ ,  $V_{BB}$ , GND,  $+V_{S}$ ,  $-V_{S}$ ,  $V_{REF}$ , etc).

## 3.4 Pin combinations to be tested.

- a. Each pin individually connected to terminal A with respect to the device ground pin(s) connected to terminal B. All pins except the one being tested and the ground pin(s) shall be open.
- b. Each pin individually connected to terminal A with respect to each different set of a combination of all named power supply pins (e.g., \( \lambda\_{S1} \), or \( \lambda\_{S2} \) or \( \lambda\_{S3} \) or \( \lambda\_{CC1} \), or \( \lambda\_{CC2} \)) connected to terminal B. All pins except the one being tested and the power supply pin or set of pins shall be open.
- c. Each input and each output individually connected to terminal A with respect to a combination of all the other input and output pins connected to terminal B. All pins except the input or output pin being tested and the combination of all the other input and output pins shall be open.



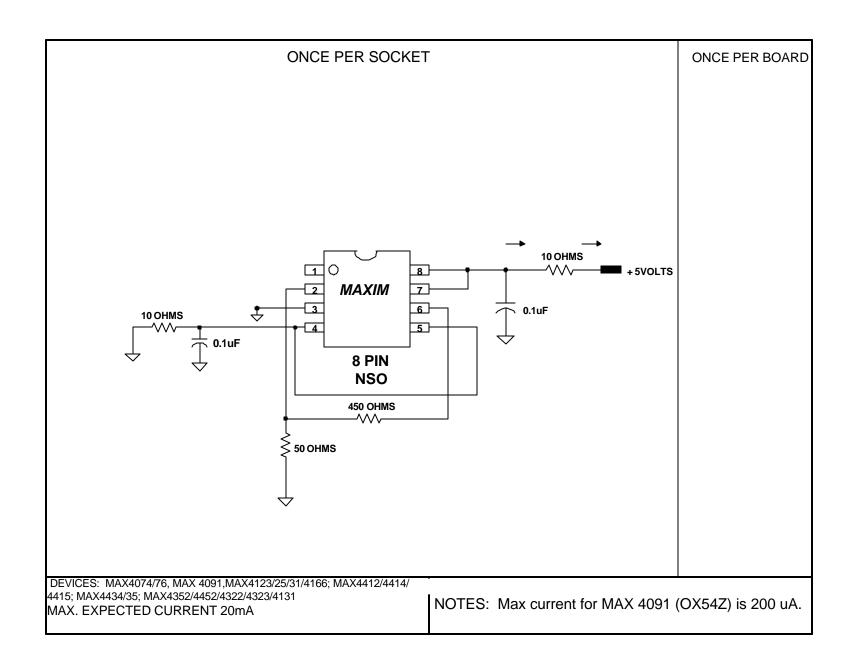
Mil Std 883D Method 3015.7 Notice 8



Ø- BONDING AREA

NOTE: CAVITY DOWN

PKG,CODE: U5-1		APPROVALS	DATE	NAXI	111
CAV./PAD SIZE:	PKG.			BUILDSHEET NUMBER:	REV.:
64X45	DESIGN			05-3001-0040	В



<b>DOCUMENT I.D.</b> 06-5215	<b>REVISION</b> G	MAXIM TITLE: BI Circuit (MAX 4074/4076/4091/4123/25/31/4166/4412/4414/4415/4434/4435/4352/4452/4322/4323/41	PAGE 2 OF 3
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